

#### **Features**

- · Split Gate Trench MOSFET Technology
- Low R<sub>DS(on)</sub> & FOM
- · Excellent Stability and Uniformity
- · Extremely Low Switching Loss
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## **Maximum Ratings**

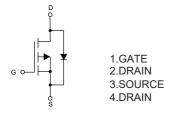
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 105°C/W Junction to Ambient
- Thermal Resistance: 1.75°C/W Junction to Case

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V <sub>DS</sub>	-100	V
Gate-Source Volltage		V <sub>GS</sub>	±20	V
Continuous Drain Current	T <sub>C</sub> =25°C	1	-18	Α
	T <sub>C</sub> =100°C	- I <sub>D</sub>	-12	Α
Pulsed Drain Current (1)		I <sub>DM</sub>	-72	Α
Avalanche Energy <sup>(2)</sup>		E <sub>AS</sub>	100	mJ
Total Power Dissipation		P <sub>D</sub>	70	W

#### Note:

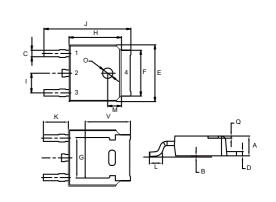
- 1. Pulse Test: Pulse Width≤300µs,Duty Cycle ≤2%.
- 2.  $T_J$ =25°C,  $V_{DD}$ =-50V,  $V_G$ =-10V, L=0.5mH,  $R_g$ =25 $\Omega$ .

#### **Internal Structure**



# P-CHANNEL MOSFET

### **DPAK**



	DIMENSIONS					
DIM	INC	INCHES		М	NOTE	
DIIVI	MIN	MAX	MIN MAX		NOTE	
Α	0.087	0.094	2.20	2.40		
В	0.000	0.005	0.00	0.13		
С	0.026	0.034	0.66	0.86		
D	0.018	0.023	0.46	0.58		
Е	0.256	0.264	6.50	6.70		
F	0.201	0.215	5.10	5.46		
G	0.190		4.83		TYP.	
Н	0.236	0.244	6.00	6.20		
I	0.086	0.094	2.18	2.39		
J	0.386	0.409	9.80	10.40		
K	0.1	14	2.9	90	TYP.	
L	0.055	0.067	1.40	1.70		
М	0.063		1.60		TYP.	
0	0.043	0.051	1.10	1.30		
Q	0.000	0.012	0.00	0.30		
V	0.211		5.35		TYP.	

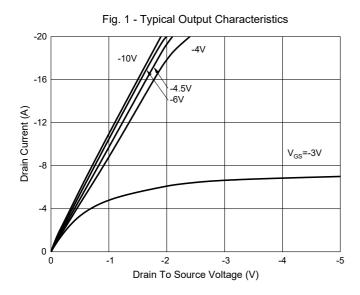


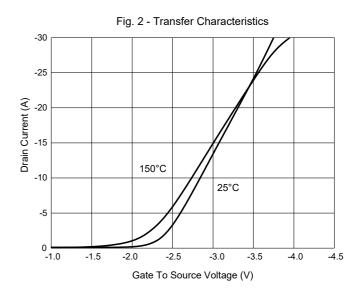
# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

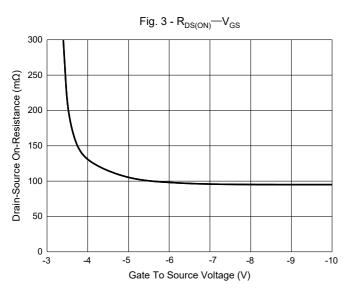
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics					1		
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-100			V	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-100V, V <sub>GS</sub> =0V			-1	μA	
		V <sub>DS</sub> =-100V, V <sub>GS</sub> =0V, T <sub>J</sub> =55°C			-5	μA	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1	-1.8	-2.5	V	
Drain-Source On-Resistance		V <sub>GS</sub> =-10V, I <sub>D</sub> =-10A		90	110	mΩ	
	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-5A		100	130	mΩ	
Diode Characteristics			•				
Continuous Body Diode Current	Is				-18	Α	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =-10A			-1.5	V	
Reverse Recovery Time	t <sub>rr</sub>	L = 5A di/dt=100A/ug		70		ns	
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>S</sub> =-5A,di/dt=100A/μs		140		nC	
Dynamic Characteristics			•				
Input Capacitance	C <sub>iss</sub>			1050			
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =-80V,V <sub>GS</sub> =0V,f=1MHz		97		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			18		1	
Total Gate Charge	Q <sub>g</sub>			20			
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-50V,V <sub>GS</sub> =-10V,I <sub>D</sub> =-5A		3.9		nC	
Gate-Drain Charge	$Q_{gd}$			4.3			
Turn-On Delay Time	t <sub>d(on)</sub>			10			
Turn-On Rise Time	t <sub>r</sub>	$V_{GS}$ =-10V, $V_{DD}$ =-50V, $R_{L}$ =2.5 $\Omega$		30			
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{GEN}=6\Omega$		77		- ns -	
Turn-Off Fall Time	t <sub>f</sub>			81			

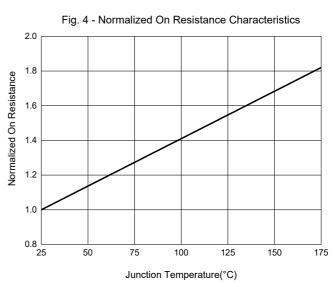


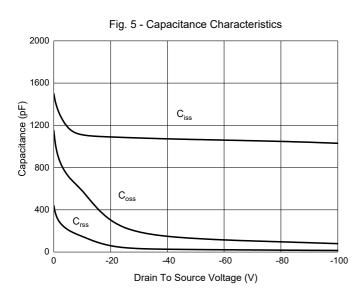
#### **Curve Characteristics**

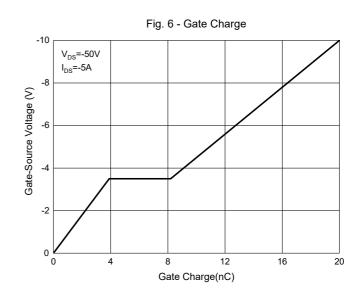






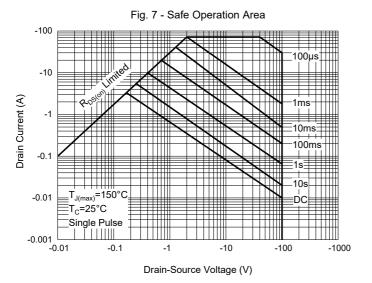








#### **Curve Characteristics**





#### **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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